Polarization isolation for GaN electronics

Yijun Dai

Ningbo Institute of Materials Technology and Engineering, CAS

Wei Guo (✉ guowei@nimte.ac.cn)

Ningbo Institute of Materials Technology and Engineering, CAS

Li Chen

Ningbo Institute of Materials Technology and Engineering, CAS

Houqiang Xu

Ningbo Institute of Materials Technology and Engineering, CAS

Feras AlQatari

King Abdullah University of Science and Technology

Chenyu Guo

Ningbo Institute of Materials Technology and Engineering, CAS

Xianchuan Peng

Ningbo Institute of Materials Technology and Engineering, CAS

Ke Tang

Ningbo Institute of Materials Technology and Engineering, CAS

Che-Hao Liao

King Abdullah University of Science and Technology

Xiaohang Li

King Abdullah University of Science and Technology

Jichun Ye

Ningbo Institute of Materials Technology and Engineering, CAS

Keywords:

Posted Date: August 10th, 2021

DOI: <https://doi.org/10.21203/rs.3.rs-740676/v1>

License: This work is licensed under a Creative Commons Attribution 4.0 International License.

[Read Full License](#)

Abstract

The authors have requested that this preprint be removed from Research Square.